

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

# RL151G THRU RL157G

GLASS PASSIVATED JUNCTION RECTIFIER

TECHNICAL SPECIFICATION

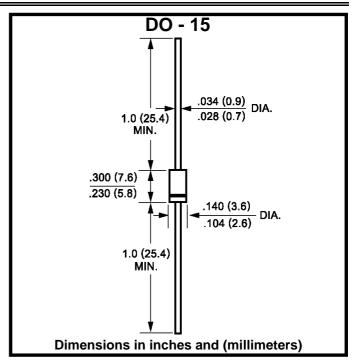
VOLTAGE: 50 TO 1000V CURRENT: 1.5A

#### **FEATURES**

- Molded case feature for auto insertion
- Glass passivated chip
- High current capability
- Low leakage current
- High surge capability
- High temperature soldering guaranteed: 250°C/10sec/0.375"(9.5mm) lead length at 5 lbs tension

## **MECHANICAL DATA**

- Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode
- Mounting position: Any



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

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RATINGS	SYMBOL	RL 151G	RL 152G	RL 153G	RL 154G	RL 155G	RL 156G	RL 157G	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current (9.5mm lead length, at T <sub>a</sub> =75°C)	I <sub>F(AV)</sub>	1.5							Α
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I <sub>FSM</sub>	60.0							Α
Maximum Instantaneous Forward Voltage (at rated forward current)	$V_{F}$	1.1							V
Maximum DC Reverse Current T <sub>a</sub> =25°C		5.0							μΑ
(at rated DC blocking voltage) T <sub>a</sub> =100°C	I <sub>R</sub>	50							μΑ
Typical Junction Capacitance (Note 1)	$C_J$	20.0							pF
Typical Thermal Resistance (Note 2)	$R_{\theta}(ja)$	40							°C/W
Storage and Operation Junction Temperature	$T_{STG},T_{J}$	-65 to +150						°C	
M. C.									*

- Note:
  - 1.Measured at 1.0 MHz and applied voltage of 4.0V<sub>dc</sub>
  - 2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C. board mounted